

## Device Electronics For Integrated Circuits 2nd Edition

A practical guide to the effects of radiation on semiconductor components of electronic systems, and techniques for the designing, laying out, and testing of hardened integrated circuits This book teaches the fundamentals of radiation environments and their effects on electronic components, as well as how to design, lay out, and test cost-effective hardened semiconductor chips not only for today's space systems but for commercial terrestrial applications as well. It provides a historical perspective, the fundamental science of radiation, and the basics of semiconductors, as well as radiation-induced failure mechanisms in semiconductor chips. Integrated Circuits Design for Radiation Environments starts by introducing readers to semiconductors and radiation environments (including space, atmospheric, and terrestrial environments) followed by circuit design and layout. The book introduces radiation effects phenomena including single-event effects, total ionizing dose damage and displacement damage) and shows how technological solutions can address both phenomena. Describes the fundamentals of radiation environments and their effects on electronic components Teaches readers how to design, lay out and test cost-effective hardened semiconductor chips for space systems and commercial terrestrial applications Covers natural and man-made radiation environments, space systems and commercial terrestrial applications Provides up-to-date coverage of state-of-the-art of radiation hardening technology in one concise volume Includes questions and answers for the reader to test their knowledge Integrated Circuits Design for Radiation Environments will appeal to researchers and product developers in the semiconductor, space, and defense industries, as well as electronic engineers in the medical field. The book is also helpful for system, layout, process, device, reliability, applications, ESD, latchup and circuit design semiconductor engineers, along with anyone involved in micro-electronics used in harsh environments.

Designed Primarily For Courses In Operational Amplifier And Linear Integrated Circuits For Electrical, Electronic, Instrumentation And Computer Engineering And Applied Science Students. Includes Detailed Coverage Of Fabrication Technology Of Integrated Circuits. Basic Principles Of Operational Amplifier, Internal Construction And Applications Have Been Discussed. Important Linear Ics Such As 555 Timer, 565 Phase-Locked Loop, Linear Voltage Regulator Ics 78/79 Xx And 723 Series D-A And A-D Converters Have Been Discussed In Individual Chapters. Each Topic Is Covered In Depth. Large Number Of Solved Problems, Review Questions And Experiments Are Given With Each Chapter For Better Understanding Of Text. Salient Features Of Second Edition \* Additional Information Provided Wherever Necessary To Improve The Understanding Of Linear Ics. \* Chapter 2 Has Been Thoroughly Revised. \* Dc & Ac Analysis Of Differential Amplifier Has Been Discussed In Detail. \* The Section On Current Mirrors Has Been Thoroughly Updated. \* More Solved

Examples, Pspice Programs And Answers To Selected Problems Have Been Added.

For some time there has been a need for a semiconductor device book that carries diode and transistor theory beyond an introductory level and yet has space to touch on a wider range of semiconductor device principles and applications. Such topics are covered in specialized monographs numbering many hundreds, but the voluminous nature of this literature limits access for students. This book is the outcome of attempts to develop a broad course on devices and integrated electronics for university students at about senior-year level. The educational prerequisites are an introductory course in semiconductor junction and transistor concepts, and a course on analog and digital circuits that has introduced the concepts of rectification, amplification, oscillators, modulation and logic and Switching circuits. The book should also be of value to professional engineers and physicists because of both, the information included and the detailed guide to the literature given by the references. The aim has been to bring some measure of order into the subject area examined and to provide a basic structure from which teachers may develop themes that are of most interest to students and themselves. Semiconductor devices and integrated circuits are reviewed and fundamental factors that control power levels, frequency, speed, size and cost are discussed. The text also briefly mentions how devices are used and presents circuits and comments on representative applications. Thus, the book seeks a balance between the extremes of device physics and circuit design.

In Optoelectronic Integrated Circuit Design and Device Modeling, Professor Jianjun Gao introduces the fundamentals and modeling techniques of optoelectronic devices used in high-speed optical transmission systems. Gao covers electronic circuit elements such as FET, HBT, MOSFET, as well as design techniques for advanced optical transmitter and receiver front-end circuits. The book includes an overview of optical communication systems and computer-aided optoelectronic IC design before going over the basic concept of laser diodes. This is followed by modeling and parameter extraction techniques of lasers and photodiodes. Gao covers high-speed electronic semiconductor devices, optical transmitter design, and optical receiver design in the final three chapters. Addresses a gap within the rapidly growing area of transmitter and receiver modeling in OEICs Explains diode physics before device modeling, helping readers understand their equivalent circuit models Provides comprehensive explanations for E/O and O/E conversions done with laser and photodiodes Covers an extensive range of devices for high-speed applications Accessible for students new to microwaves Presentation slides available for instructor use This book is primarily aimed at practicing engineers, researchers, and post-graduates in the areas of RF, microwaves, IC design, photonics and lasers, and solid state devices. The book is also a strong supplement for senior undergraduates taking courses in RF and microwaves. Lecture materials for instructors available at [www.wiley.com/go/gao](http://www.wiley.com/go/gao)

Electronic Devices and Circuits, Volume 2 provides a comprehensive coverage of the concepts involved in electronic devices and circuitries. The text first details the network theory, and then proceeds to covering electronics in the succeeding chapters. The coverage of the book includes transmission lines; high-frequency valves and transistors; amplifiers; oscillators; and multivibrator and trigger circuits. The text also covers several concerns in electronics, such as the physics of semiconductor devices; stabilization of power supplies; and feedback. The book will be of great use to students of electrical engineering and other electronics related degree.

Semiconductor Device Physics and Design teaches readers how to approach device design from the point of view of someone who wants to improve devices and can see the opportunity and challenges. It begins with coverage of basic physics concepts, including the physics behind polar heterostructures and strained heterostructures. The book then details the important devices ranging from p-n diodes to bipolar and field effect devices. By relating device design to device performance and then relating device needs to system use the student can see how device design works in the real world.

This graduate-level textbook presents the principles, design methods, simulation, and materials of photonic circuits. It provides state-of-the-art examples of silicon, indium phosphide, and other materials frequently used in these circuits, and includes a thorough discussion of all major types of devices. In addition, the book discusses the integrated photonic circuits (chips) that are currently increasingly employed on the international technology market in connection with short-range and long-range data communication. Featuring references from the latest research in the field, as well as chapter-end summaries and problem sets, Principles of Photonic Integrated Circuits is ideal for any graduate-level course on integrated photonics, or optical technology and communication.

This book, now in its Second Edition, provides a basis for understanding the characteristics, working principle, operation and limitations of semi-conductor devices. In this new edition, many sections are re-written to present the concepts related to device physics in more clearer and easy to understand manner. The primary objective of this textbook is to provide all the relevant topics on the semiconductor materials and semiconductor devices in a single volume. It includes enough mathematical expressions to provide a good foundation for the basic understanding of the semiconductor devices. It covers not only the state-of-the-art devices but also future approaches that go beyond the current technology. Designed primarily as a text for the postgraduate students of physics and electronics, the book would also be useful for the undergraduate students of electronics and electrical engineering, and electronics and communication engineering. Highlights of the Book : Includes topics on the latest technologies Covers important points in each chapter Provides a number of solved and unsolved problems along with explanation type questions Emphasizes on the mathematical derivation

Physics of Semiconductor Devices covers both basic classic topics such as energy band theory and the gradual-channel model of the MOSFET as well as advanced concepts and devices such as MOSFET short-channel effects, low-dimensional devices and single-electron

transistors. Concepts are introduced to the reader in a simple way, often using comparisons to everyday-life experiences such as simple fluid mechanics. They are then explained in depth and mathematical developments are fully described. Physics of Semiconductor Devices contains a list of problems that can be used as homework assignments or can be solved in class to exemplify the theory. Many of these problems make use of Matlab and are aimed at illustrating theoretical concepts in a graphical manner.

Market\_Desc: · Electrical Engineers Special Features: · Over 150 solved examples that clarify concepts are integrated throughout the text. · End-of-chapter summary tables and hundreds of figures are included to reinforce the intricacies of modern semiconductor devices· Coverage of device optimization issues shows the reader how in each device one has to trade one performance against another About The Book: This introductory text presents a well-balanced coverage of semiconductor physics and device operation and shows how devices are optimized for applications. The text begins with an exploration of the basic physical processes upon which all semiconductor devices are based. Next, the author focuses on the operation of the important semiconductor devices along with issues relating to the optimization of device performance. Offering a single volume reference for high frequency semiconductor devices, this handbook covers basic material characteristics, system level concerns and constraints, simulation and modeling of devices, and packaging. Individual chapters detail the properties and characteristics of each semiconductor device type, including: Varactors, Schottky diodes, transit-time devices, BJTs, HBTs, MOSFETs, MESFETs, and HEMTs. Written by leading researchers in the field, the RF and Microwave Semiconductor Device Handbook provides an excellent starting point for programs involving development, technology comparison, or acquisition of RF and wireless semiconductor devices.

A detailed, modern introduction to semiconductors made in silicon and III-V compounds. This book develops the device physics of pn junctions, bipolar transistors, Schottky barriers, MOS capacitors, and MOS field-effect transistors (MOSFETs). Basic concepts from quantum and statistical mechanics are used to describe electrons and holes in semiconductors. Figures and examples based on realistic device parameters are used to illustrate important concepts. The book uses spice tools to analyze complex devices. Design specifications are stressed in building or modeling complicated semiconductor devices.

If you need a book that relates the core principles of quantum mechanics to modern applications in engineering, physics, and nanotechnology, this is it. Students will appreciate the book's applied emphasis, which illustrates theoretical concepts with examples of nanostructured materials, optics, and semiconductor devices. The many worked examples and more than 160 homework problems help students to problem solve and to practise applications of theory. Without assuming a prior knowledge of high-level physics or classical mechanics, the text introduces Schrödinger's equation, operators, and approximation methods. Systems, including the hydrogen atom and crystalline materials, are analyzed in detail. More advanced subjects, such as density matrices, quantum optics, and quantum information, are also covered. Practical applications and algorithms for the computational analysis of simple structures make this an ideal introduction to quantum mechanics for students of engineering, physics, nanotechnology, and other disciplines. Additional resources available from [www.cambridge.org/9780521897839](http://www.cambridge.org/9780521897839).

A reprint of the classic text, this book popularized compact modeling of electronic and semiconductor devices and components for college and graduate-school classrooms, and manufacturing engineering, over a decade ago. The first comprehensive book on MOS transistor compact modeling, it was the most cited among similar books in the area and remains the most frequently cited today. The coverage is device-physics based and continues to be relevant to the latest advances in MOS transistor modeling. This is also the only book that

discusses in detail how to measure device model parameters required for circuit simulations. The book deals with the MOS Field Effect Transistor (MOSFET) models that are derived from basic semiconductor theory. Various models are developed, ranging from simple to more sophisticated models that take into account new physical effects observed in submicron transistors used in today's (1993) MOS VLSI technology. The assumptions used to arrive at the models are emphasized so that the accuracy of the models in describing the device characteristics are clearly understood. Due to the importance of designing reliable circuits, device reliability models are also covered. Understanding these models is essential when designing circuits for state-of-the-art MOS ICs.

### Device Electronics for Integrated Circuits Wiley

Low-Voltage Low-Power Analog Integrated Circuits brings together in one place important contributions and state-of-the-art research results in this rapidly advancing area. Low-Voltage Low-Power Analog Integrated Circuits serves as an excellent reference, providing insight into some of the most important issues in the field.

With the advent of integrated circuit technology, the importance and usefulness of digital electronics has vastly increased. The size, cost and power dissipation have been reduced in the ratio of 2,000:1 and the performance, reliability and efficiency of equipment increased tremendously. This book gives a basic concept of digital techniques and then introduces simple function to complex functions. It uses SSI and MSI, TTL ICs of the most commonly available 54/74 series. The book will be useful to students of electronics and computer technology, as well as to practicing engineers and technicians.

This book provides a detailed treatment of radiation effects in electronic devices, including effects at the material, device, and circuit levels. The emphasis is on transient effects caused by single ionizing particles (single-event effects and soft errors) and effects produced by the cumulative energy deposited by the radiation (total ionizing dose effects). Bipolar (Si and SiGe), metal-oxide-semiconductor (MOS), and compound semi-conductor technologies are discussed. In addition to considering the specific issues associated with high-performance devices and technologies, the book includes the background material necessary for understanding radiation effects at a more general level.

Reviews the fundamental concepts behind the theory and computation of electromagnetic fields The book is divided in two parts. The first part covers both fundamental theories (such as vector analysis, Maxwell's equations, boundary condition, and transmission line theory) and advanced topics (such as wave transformation, addition theorems, and fields in layered media) in order to benefit students at all levels. The second part of the book covers the major computational methods for numerical analysis of electromagnetic fields for engineering applications. These methods include the three fundamental approaches for numerical analysis of electromagnetic fields: the finite difference method (the finite difference time-domain method in particular), the finite element method, and the integral equation-based moment method. The second part also examines fast algorithms for solving integral equations and hybrid techniques that combine

different numerical methods to seek more efficient solutions of complicated electromagnetic problems. Theory and Computation of Electromagnetic Fields, Second Edition: Provides the foundation necessary for graduate students to learn and understand more advanced topics Discusses electromagnetic analysis in rectangular, cylindrical and spherical coordinates Covers computational electromagnetics in both frequency and time domains Includes new and updated homework problems and examples Theory and Computation of Electromagnetic Fields, Second Edition is written for advanced undergraduate and graduate level electrical engineering students. This book can also be used as a reference for professional engineers interested in learning about analysis and computation skills.

This book provides all the required information for a course in modern device electronics taken by undergraduate electrical engineers. It offers coverage of silicon technology, several topics in basic semiconductor physics, and Hall-effect sensors. The chapters on MOSFET focus on mobility variations and threshold-voltage dependence. Additional topics include VLSI devices, short channel effects, and computer modeling. · Semiconductor Electronics · Silicon Technology · Metal-Semiconductor Contacts · pn Junctions · Currents in pn Junctions · Bipolar Transistors I: Basic Properties · Bipolar Transistors II: Limitations and Models · Properties of the Metal-Oxide-Silicon System · Mos Field-Effect Transistors I: Physical Effects and Models · Mos Field-Effect Transistors II: High-Field Effects

From power electronics to power integrated circuits (PICs), smart power technologies, devices, and beyond, Integrated Power Devices and TCAD Simulation provides a complete picture of the power management and semiconductor industry. An essential reference for power device engineering students and professionals, the book not only describes the physics inside integrated power semiconductor devices such lateral double-diffused metal oxide semiconductor field-effect transistors (LDMOSFETs), lateral insulated-gate bipolar transistors (LIGBTs), and super junction LDMOSFETs but also delivers a simple introduction to power management systems. Instead of abstract theoretical treatments and daunting equations, the text uses technology computer-aided design (TCAD) simulation examples to explain the design of integrated power semiconductor devices. It also explores next generation power devices such as gallium nitride power high electron mobility transistors (GaN power HEMTs). Including a virtual process flow for smart PIC technology as well as a hard-to-find technology development organization chart, Integrated Power Devices and TCAD Simulation gives students and junior engineers a head start in the field of power semiconductor devices while helping to fill the gap between power device engineering and power management systems.

Praise for CMOS: Circuit Design, Layout, and Simulation Revised Second Edition from the Technical Reviewers "A refreshing industrial flavor. Design concepts are presented as they are needed for 'just-in-time' learning. Simulating and designing circuits using SPICE is emphasized with literally hundreds of examples. Very few textbooks contain as much

detail as this one. Highly recommended!" --Paul M. Furth, New Mexico State University "This book builds a solid knowledge of CMOS circuit design from the ground up. With coverage of process integration, layout, analog and digital models, noise mechanisms, memory circuits, references, amplifiers, PLLs/DLLs, dynamic circuits, and data converters, the text is an excellent reference for both experienced and novice designers alike." --Tyler J. Gomm, Design Engineer, Micron Technology, Inc. "The Second Edition builds upon the success of the first with new chapters that cover additional material such as oversampled converters and non-volatile memories. This is becoming the de facto standard textbook to have on every analog and mixed-signal designer's bookshelf." --Joe Walsh, Design Engineer, AMI Semiconductor CMOS circuits from design to implementation CMOS: Circuit Design, Layout, and Simulation, Revised Second Edition covers the practical design of both analog and digital integrated circuits, offering a vital, contemporary view of a wide range of analog/digital circuit blocks, the BSIM model, data converter architectures, and much more. This edition takes a two-path approach to the topics: design techniques are developed for both long- and short-channel CMOS technologies and then compared. The results are multidimensional explanations that allow readers to gain deep insight into the design process. Features include: Updated materials to reflect CMOS technology's movement into nanometer sizes Discussions on phase- and delay-locked loops, mixed-signal circuits, data converters, and circuit noise More than 1,000 figures, 200 examples, and over 500 end-of-chapter problems In-depth coverage of both analog and digital circuit-level design techniques Real-world process parameters and design rules The book's Web site, CMOSedu.com, provides: solutions to the book's problems; additional homework problems without solutions; SPICE simulation examples using HSPICE, LTspice, and WinSpice; layout tools and examples for actually fabricating a chip; and videos to aid learning Focusing specifically on silicon devices, the Third Edition of Device Electronics for Integrated Circuits takes students in integrated-circuits courses from fundamental physics to detailed device operation. Because the book focuses primarily on silicon devices, each topic can include more depth, and extensive worked examples and practice problems ensure that students understand the details.

A transistor-level, design-intensive overview of high speed and high frequency monolithic integrated circuits for wireless and broadband systems from 2 GHz to 200 GHz, this comprehensive text covers high-speed, RF, mm-wave, and optical fibre circuits using nanoscale CMOS, SiGe BiCMOS, and III-V technologies. Step-by-step design methodologies, end-of chapter problems, and practical simulation and design projects are provided, making this an ideal resource for senior undergraduate and graduate courses in circuit design. With an emphasis on device-circuit topology interaction and optimization, it gives circuit designers and students alike an in-depth understanding of device structures and process limitations affecting circuit performance.

Includes plenty of design examples together with the key issues encountered in real-world design scenarios, for students and practising engineers.

Power Management Integrated Circuits and Technologies delivers a modern treatise on mixed-signal integrated circuit design for power management. Comprised of chapters authored by leading researchers from industry and academia, this definitive text: Describes circuit- and architectural-level innovations that meet advanced power and speed capabilities Explores hybrid inductive-capacitive converters for wide-range dynamic voltage scaling Presents innovative control techniques for single inductor dual output (SIDO) and single inductor multiple output (SIMO) converters Discusses cutting-edge design techniques including switching converters for analog/RF loads Compares the use of GaAs pHEMTs to CMOS devices for efficient high-frequency switching converters Thus, Power Management Integrated Circuits and Technologies provides comprehensive, state-of-the-art coverage of this exciting and emerging field of engineering. The book summarizes and compares recent advancements in the development of novel lateral power transistors (LDMOS devices) for integrated circuits in power electronic applications. In its first part, the book motivates the necessity for lateral power transistors by a top-down approach: First, it presents typical energy conversion applications in modern industrial, automotive and consumer electronics. Next, it introduces common circuit topologies suitable for these applications, and discusses the feasibility for monolithic integration. Finally, the combination of power and logic functionality on a single chip is motivated and the requirements and limitations for the power semiconductor devices are deduced. The second part describes the evolution of lateral power transistors over the past decades from the simple pin-type concept to double-acting RESURF topologies. It describes the principle of operation for these LDMOS devices and discusses limitations of lateral power devices. Moreover, figures-of-merit are presented which can be used to evaluate the performance of the novel lateral power transistors described in this book with respect to the LDMOS devices. In the last part, [...] the fundamental physical concepts including charge compensation and trench gate topologies are discussed. Also, the status of research in LDMOS devices on silicon carbide is presented. Advantages and drawbacks for each of these integration approaches are summarized, and the feasibility with respect to power electronic applications is evaluated.

This Second Edition provides all the required information for a course in modern device electronics taken by undergraduate electrical engineers. Offers major new coverage of silicon technology, adds several topics in basic semiconductor physics not treated previously, and introduces Hall-effect sensors. The chapters on MOSFET have been entirely updated, focusing on mobility variations and threshold-voltage dependence. Additional topics include VLSI devices, short channel effects, and computer modeling.

- Explains electronics from fundamentals to applications - no other book has such breadth of coverage
- Approachable, clear writing style with minimal math - no previous knowledge of electronics required!
- Now fully revised and updated to include coverage of the latest developments in electronics: Blu-ray, HD, 3D TV, digital TV and radio, miniature computers, robotic systems and more

Electronics Simplified (previously published as Electronics Made Simple) is essential reading for students embarking on courses involving electronics, anyone whose job involves electronic technology or equipment, and anyone who wants to know more about the electronics revolution. No previous knowledge is assumed and by focusing on how systems work, rather than on details of circuit diagrams and calculations, this book introduces readers to the key principles and technology of modern electronics without needing access to expensive equipment or laboratories. This approach also enables students to gain a firm grasp of the principles they will be applying in the lab. Explains electronics from fundamentals to applications - No other book has such breadth of coverage Approachable, clear writing style, with minimal math - No previous knowledge of electronics required! Now fully revised and updated to include coverage of the latest developments in electronics: Blu-ray, HD, 3-D TV, digital TV and radio, miniature computers, robotic systems and more.

Quantum size effects are becoming increasingly important in microelectronics, as the dimensions of the structures shrink laterally towards 100 nm and vertically towards 10 nm. Advanced device concepts will exploit these effects for integrated circuits with novel or improved properties. Keeping in mind the trend towards systems on chip, this book deals with silicon-based quantum devices and focuses on room-temperature operation. The basic physical principles, materials, technological aspects, and fundamental device operation are discussed in an interdisciplinary manner. It is shown that silicon-germanium (SiGe) heterostructure devices will play a key role in realizing silicon-based quantum electronics.

The first book to deal with a broad spectrum of process and device design, and modeling issues related to semiconductor devices, bridging the gap between device modelling and process design using TCAD. Presents a comprehensive perspective of emerging fields and covers topics ranging from materials to fabrication, devices, modelling and applications. Aimed at research-and-development engineers and scientists involved in microelectronics technology and device design via Technology CAD, and TCAD engineers and developers.

Modern Semiconductor Devices for Integrated Circuits, First Edition introduces readers to the world of modern semiconductor devices with an emphasis on integrated circuit applications. KEY TOPICS: Electrons and Holes in Semiconductors; Motion and Recombination of Electrons and Holes; Device Fabrication Technology; PN and Metal–Semiconductor Junctions; MOS Capacitor; MOS Transistor; MOSFETs in ICs—Scaling, Leakage, and Other Topics; Bipolar Transistor. MARKET: Written by an experienced teacher, researcher, and expert in industry practices, this succinct and forward-looking text is appropriate for anyone interested in semiconductor devices for integrated circuits, and serves as a suitable reference text for practicing engineers.

A clear, detailed introduction to modern analog and digital electronics, complete with simulation and design exercises.

Nonlinear Electronics 1: Nonlinear Dipoles, Harmonic Oscillators and Switching Circuits deals with the appearance of nonlinear

electronic circuits and their behavior. The book studies a number of circuits that interface between analog and digital electronics, including astable, monostable, bistable, Schmitt trigger, and analog-to-digital and digital-to-analog conversion. Users will find a complete resource that deals with all aspects of these circuits, starting from the discrete component and gradually working to the integrated circuit. Presents non-linear electronic circuits and their behavior Discusses relaxation oscillators Treats subject matter from the discrete element, to the integrated device Present interface circuits, analog-to-digital conversion, analog-to-analog, and PLL (phase locked loop)

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